



Typical Applications

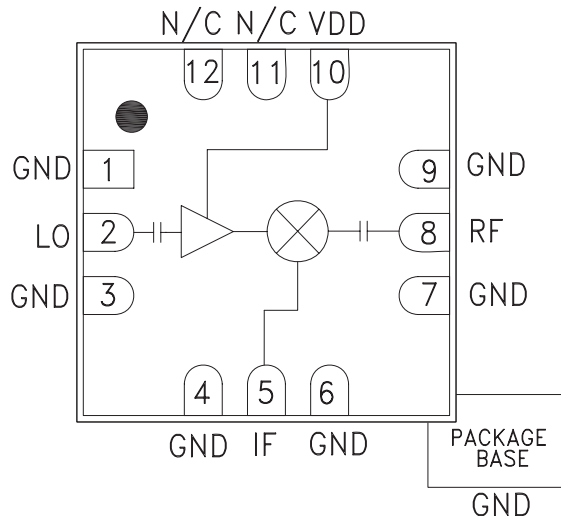
The HMC338LC3B is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios & VSAT
- Test Equipment & Sensors
- Military End-Use
- SAT COM

Features

- Integrated LO Amplifier: -5 dBm Input
- Sub-Harmonically Pumped (x2) LO
- DC - 3 GHz Wideband IF
- RoHS Compliant 3x3 mm SMT Package
- Single Positive Supply: +4V @ 31mA

Functional Diagram



General Description

The HMC338LC3B is a 24 - 34 GHz Sub-harmonically Pumped (x2) MMIC Mixer with an integrated LO amplifier in a leadless RoHS compliant SMT package. The 2LO to RF isolation is excellent at 30 dB, eliminating the need for additional filtering. The LO amplifier is a single bias (+3V to +4V) design with a nominal -5 dBm drive requirement. The RF and LO ports are DC blocked and matched to 50 Ohms for ease of use while the IF covers DC to 3 GHz. The HMC338LC3B eliminates the need for wire bonding, allowing use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25^\circ C$, As a Function of Vdd

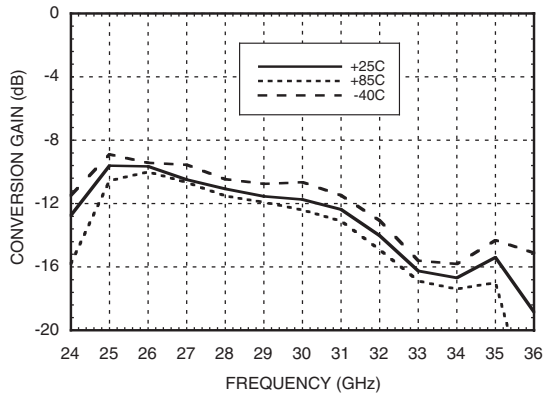
Parameter	IF = 1 GHz LO = -5 dBm & Vdd = +4V			IF = 1 GHz LO = -5 dBm & Vdd = +4V			IF = 1 GHz LO = -5 dBm & Vdd = +3V			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range, RF	24 - 27			25 - 31			31 - 34			GHz
Frequency Range, LO	11.5 - 13			12 - 15			15 - 16.5			GHz
Frequency Range, IF	DC - 3			DC - 3			DC - 3			GHz
Conversion Loss		11	15		11	15		15	18	dB
2LO to RF Isolation	25	30		25	33		30	40		dB
2LO to IF Isolation	37	45		37	50		40	50		dB
IP3 (Input)		9			13			14.5		dBm
1 dB Compression (Input)		3			5			6.5		dBm
Supply Current (Idd)		31	40		31	40		29	40	mA

*Unless otherwise noted, all measurements performed as downconverter, IF= 1 GHz.

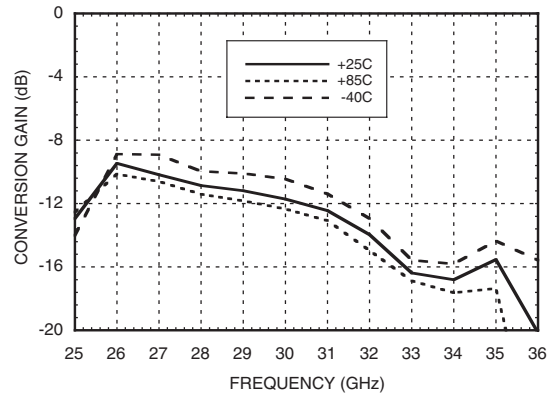


GaAs MMIC SUB-HARMONIC SMT MIXER, 24 - 34 GHz

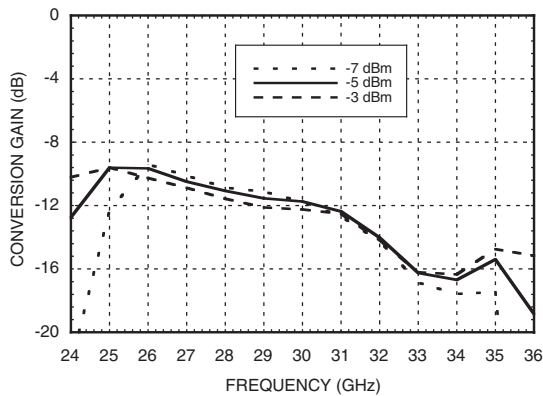
Conversion Gain vs. Temperature @ LO = -4 dBm, Vdd= +4V



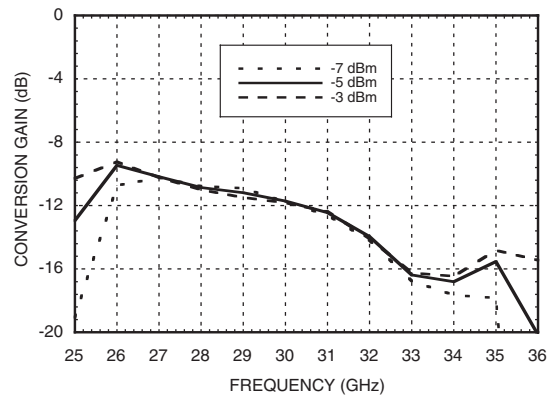
Conversion Gain vs. Temperature @ LO = -4 dBm, Vdd= +3V



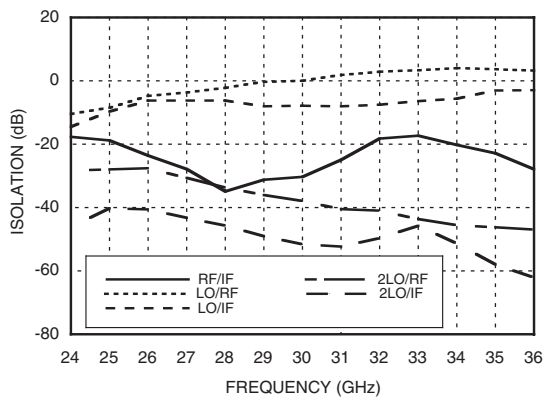
Conversion Gain vs. LO Drive @ Vdd = +4V



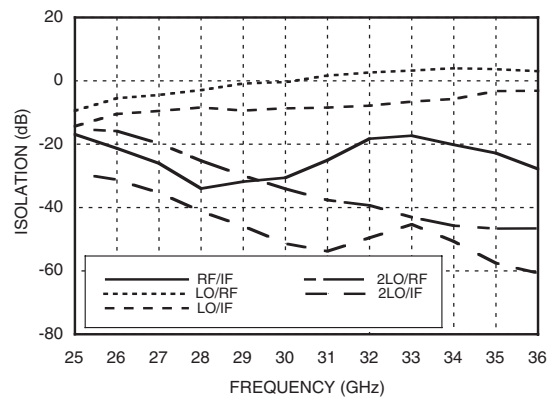
Conversion Gain vs. LO Drive @ Vdd = +3V



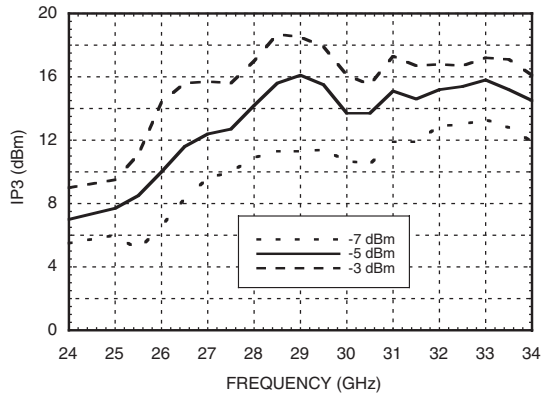
Isolation @ Vdd = +4V



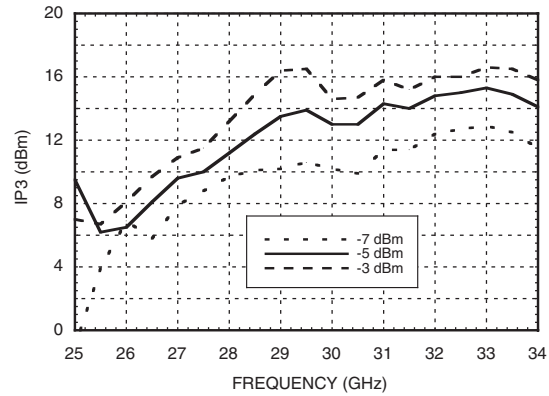
Isolation @ Vdd = +3V



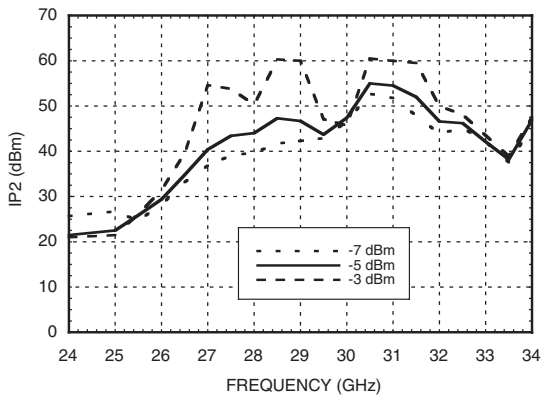
Input IP3 vs. LO Drive @ Vdd = +4V *



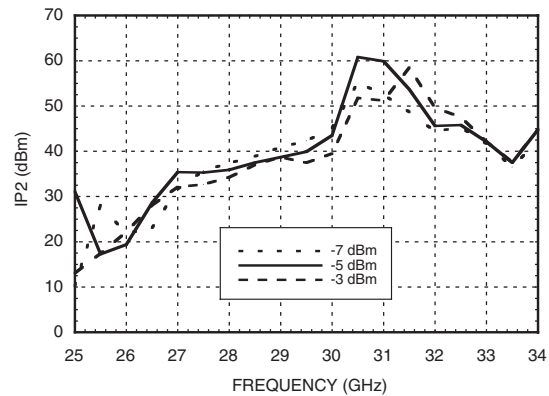
Input IP3 vs. LO Drive @ Vdd = +3V *



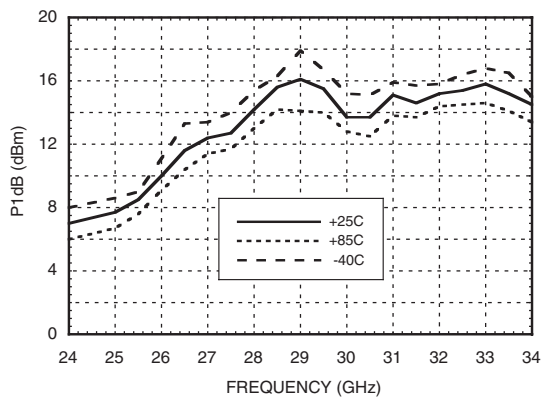
Input IP2 vs. LO Drive @ Vdd = +4V *



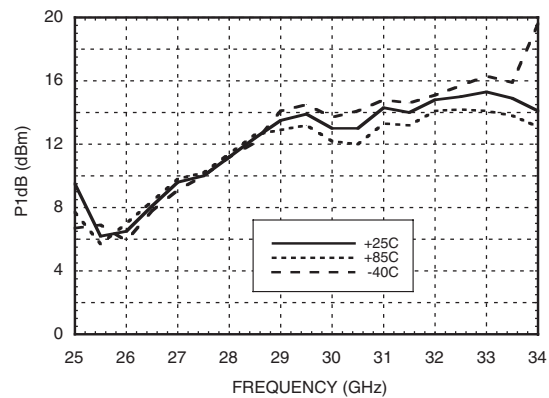
Input IP2 vs. LO Drive @ Vdd = +3V *



Input P1dB vs. Temperature @ LO = -4 dBm, Vdd = +4V



Input P1dB vs. Temperature @ LO = -4 dBm, Vdd = +3V

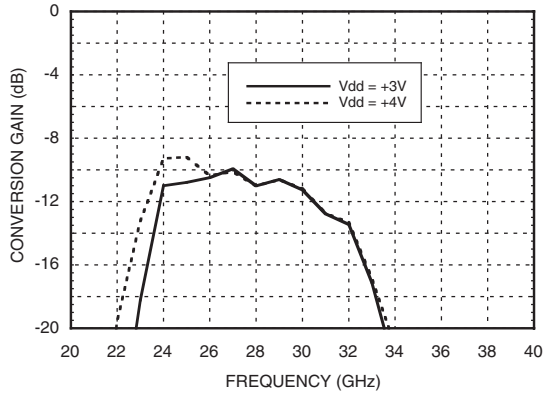


* Two-tone input power = -10 dBm each tone, 1 MHz spacing.

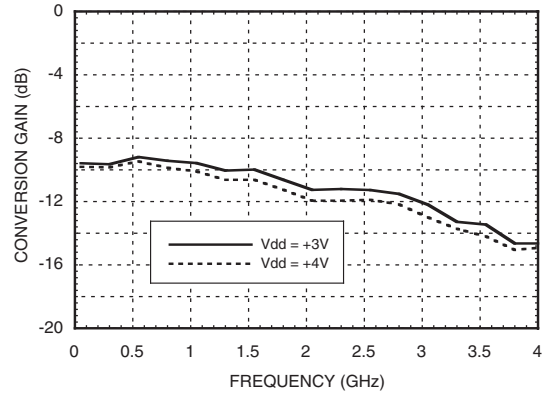


GaAs MMIC SUB-HARMONIC SMT MIXER, 24 - 34 GHz

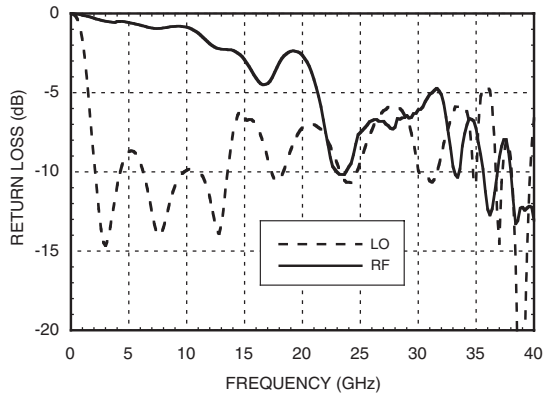
Upconverter Performance Conversion Gain @ LO = -4 dBm



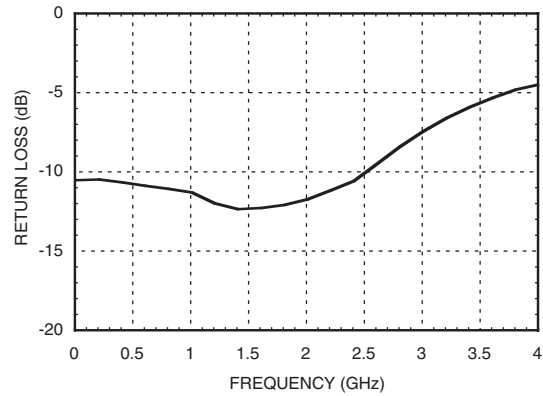
IF Bandwidth @ LO = -4 dBm



RF & LO Return Loss @ LO = -4 dBm



IF Return Loss @ LO = -4 dBm





GaAs MMIC SUB-HARMONIC SMT MIXER, 24 - 34 GHz

MxN Spurious Outputs @ IF Port, Vdd = 4V

mRF	nLO					
	±5	±4	±3	±2	±1	0
-3						
-2	62					
-1	75	42	67			
0			12	34	-8	
1				0	55	13
2		65	51		68	
3	95					

RF = 31 GHz @ -10 dBm
LO = 15 GHz @ -5 dBm
All values in dBc below IF power level (1RF - 2LO)
Measured as downconverter

MxN Spurious Outputs @ RF Port, Vdd = 4V

mIF	nLO					
	±5	±4	±3	±2	±1	0
-3				42		
-2			25	60	40	
-1			45	0	41	
0			-3	23	-17	
1			49	0	38	13
2			32	63	30	67
3				46		57

IF = 1 GHz @ -10 dBm
LO = 15 GHz @ -5 dBm
All values in dBc below IF power level (1IF - 2LO)
Measured as upconverter

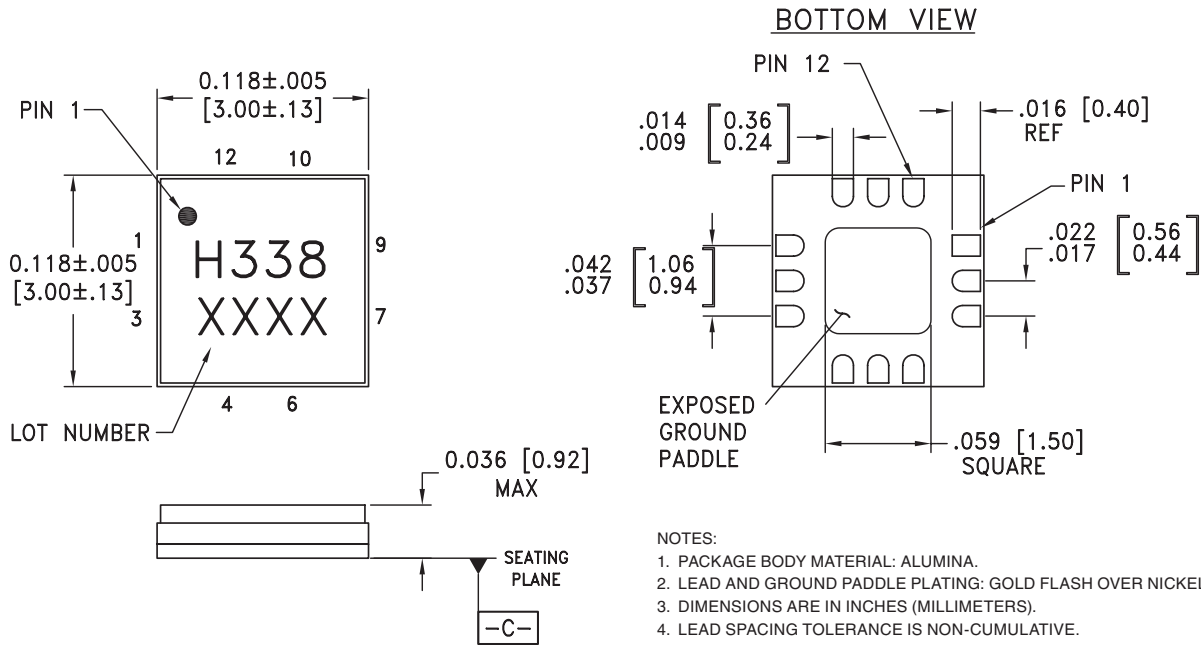
Absolute Maximum Ratings

RF / IF Input (Vdd = +5V)	+10 dBm
LO Drive (Vdd = +5V)	+13 dBm
Vdd	5.5V
Channel Temperature	175 °C
Continuous Pdiss (Ta = 85 °C) (derate 2.52 mW/°C above 85 °C)	227 mW
Thermal Resistance (junction to ground paddle)	397 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C


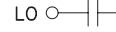
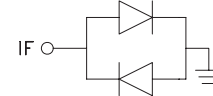
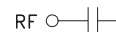


ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing

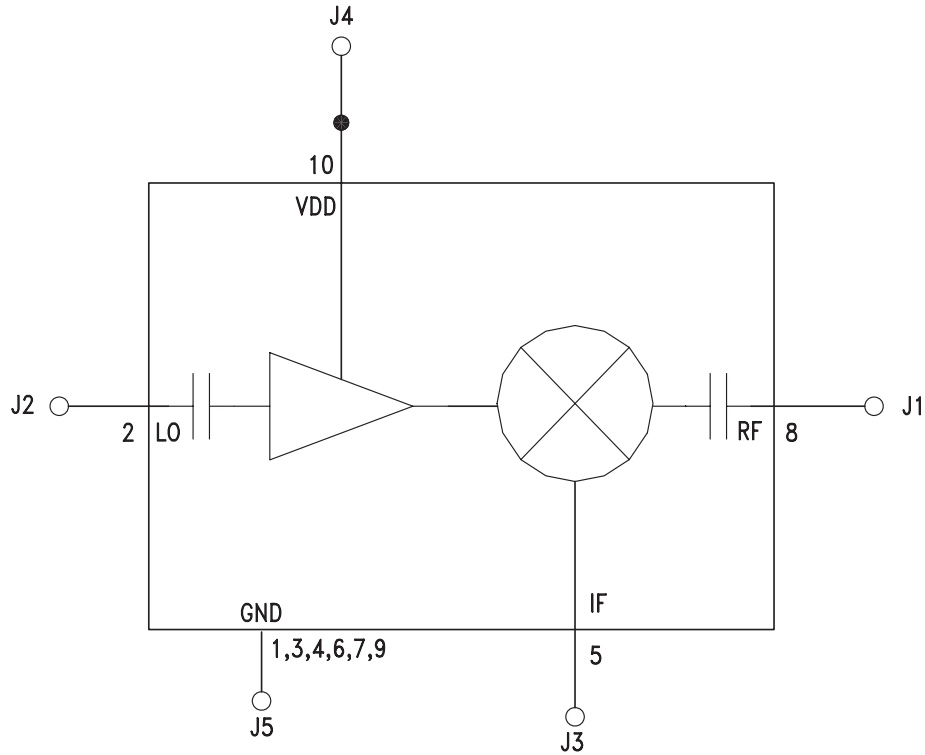


Pin Descriptions

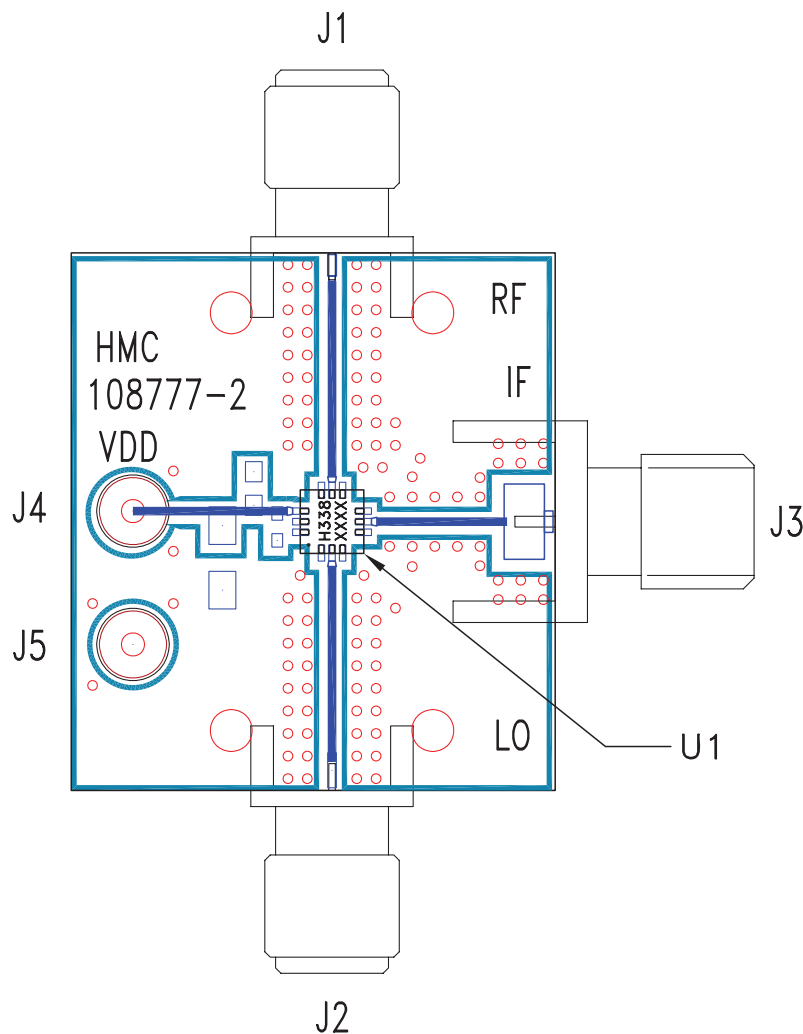
Pin Number	Function	Description	Interface Schematic
1, 3, 4, 6, 7, 9	GND	Package bottom must also be connected to RF/DC ground.	
2	LO	This pin is AC coupled and matched to 50 Ohms from 12 - 17 GHz.	
5	IF	This pin is DC coupled and should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary IF frequency range. Any applied DC voltage to this pin will result in die non-function and possible die failure.	
8	RF	This pin is AC coupled and matched to 50 Ohms from 24 - 34 GHz.	
10	Vdd	Power supply for the LO Amplifier.	
11, 12	N/C	No connection required. These pins may be connected to RF/DC ground without affecting performance.	



Application Circuit



Evaluation PCB



List of Materials for Evaluation PCB 108779 ^[1]

Item	Description
J1 - J3	PCB Mount SMA Connector
J4, J5	DC Pin
U1	HMC338LC3B Mixer
PCB [2]	108777 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

Данный компонент на территории Российской Федерации

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На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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